TELEFUNKEN electronic
Creative Technologies

T-31-25 **CF 300**

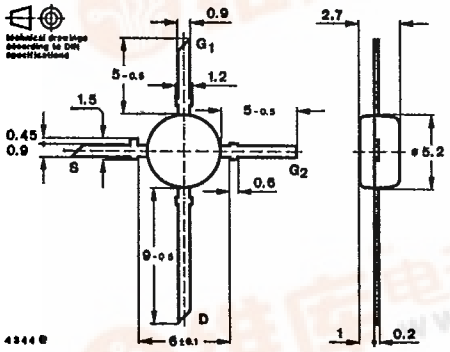
N-Channel-GaAs-MESFET-Tetrode Depletion Mode

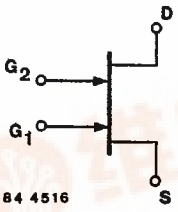
Applications: Gain controlled amplifiers and mixers up to 2 GHz in common source configuration; In wireless telephone, broadcast sets, cabel TV and equipments with low power supply.

Features:

- Low noise figure
- High gain
- Low input capacitance
- High AGC-range
- Large input signal behaviour
- Near constant characteristics in frequency range $f = 0.1 \ldots 2$ GHz
- Very low cross modulation

Dimensions in mm





Case
50 B 4 DIN 41867
JEDEC TO 50
Weight max. 0.1 g

Absolute maximum ratings

Drain Source voltage	V_{DS}	10	V
Drain current	I_D	80	mA
Gate 1/Gate 2-peak current	I_G	1	mA
Gate1/Gate 2-Source voltage	V_{GS}	6	V
Total power dissipation $T_{amb} \leq$ see page A 24, Fig. 6.3	P_{tot}	200	mW
Channel temperature	T_C	125	°C
Storage temperature range	T_{stg}	−55...+125	°C

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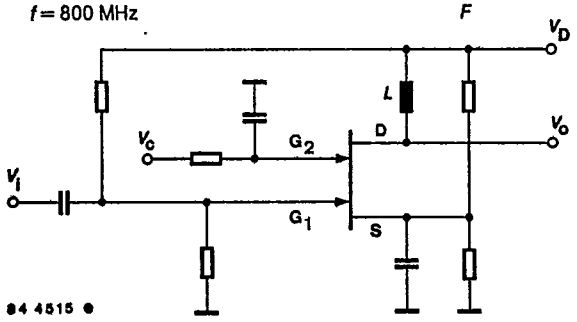
DC-Characteristics $T_{amb} = 25\,°C$		Min.	Typ.	Max.	
Drain-Source break down voltage $I_D = 50\,\mu A$, $V_{G1S} = -6\,V$, $V_{G2S} = 0$	$V_{(BR)DS}$	10			V
Gate 1-Source cut-off current $V_{G1S} = -6\,V$, $V_{DS} = V_{G2S} = 0$	I_{G1SS}			20	µA
Gate 2-Source cut-off current $V_{G2S} = -6\,V$, $V_{DS} = V_{G1S} = 0$	I_{G2SS}			20	µA
Gate 1-Source cut-off voltage $V_{DS} = 5\,V$, $V_{G2S} = 0$, $I_D = 200\,\mu A$	$-V_{G1S(p)}$		3	5	V
Gate 2-Source cut-off voltage $V_{DS} = 5\,V$, $V_{G1S} = 0$, $I_D = 200\,\mu A$	$-V_{G2S(p)}$		3	5	V
Drain current $V_{DS} = 5\,V$, $V_{G1S} = V_{G2S} = 0$	I_{DSS} [1]	10	40	80	mA
AC-Characteristics $V_{DS} = 5\,V$, $V_{G2S} = 2\,V$, $I_D = 10\,mA$, $T_{amb} = 25\,°C$					
Forward transfer admittance $f = 1\,MHz$	$\lvert y_{21} \rvert$		25		mS
Gate 1-Source capacitance $f = 1\,MHz$	C_{11}		0.9	1.2	pF
Drain-Source capacitance $f = 1\,MHz$	C_{22}		0.6	0.9	pF
Power gain $f = 800\,MHz$	G_{max}		23		dB
AGC range $V_{G2S} = +2 \ldots -6\,V$, $f = 800\,MHz$	ΔG		50		dB
Noise figure $f = 800\,MHz$	F		1.1		dB



V_c = control voltage

Typical application

[1] Available in I_{DSS}-groups on request
A: 10-35 mA, B: 30-50 mA, C: 45-80 mA

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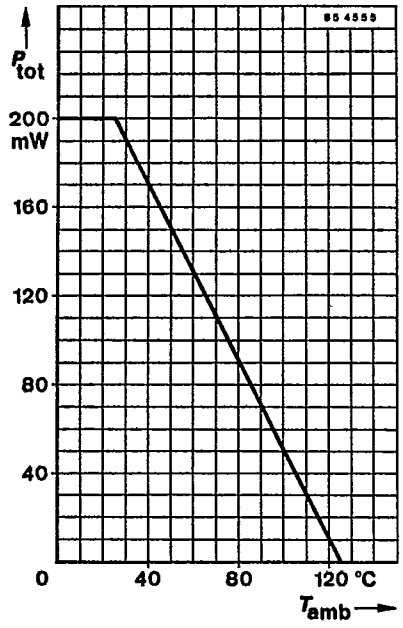

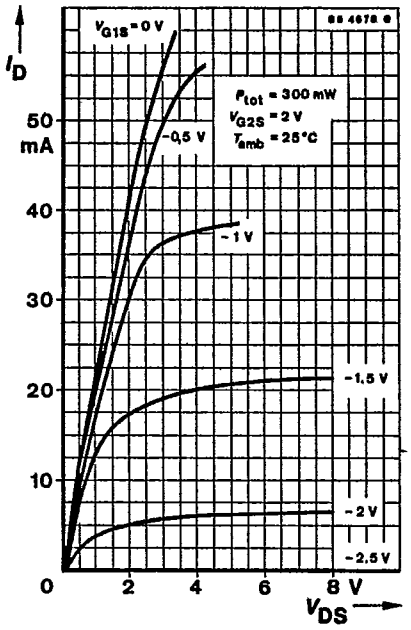

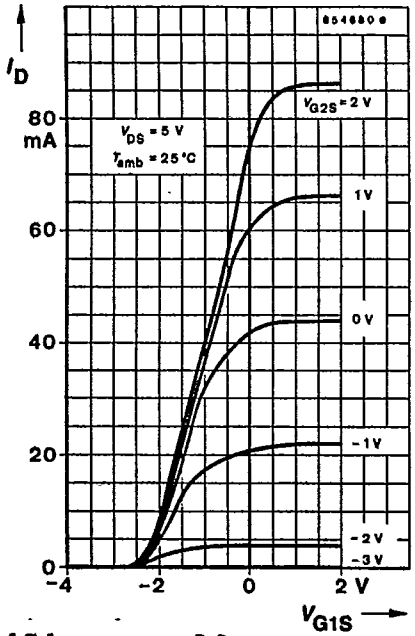

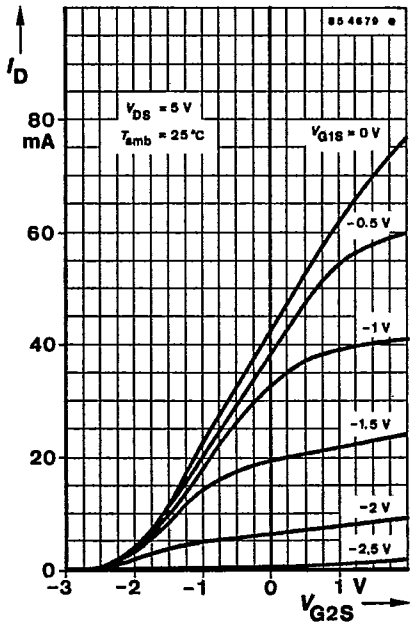

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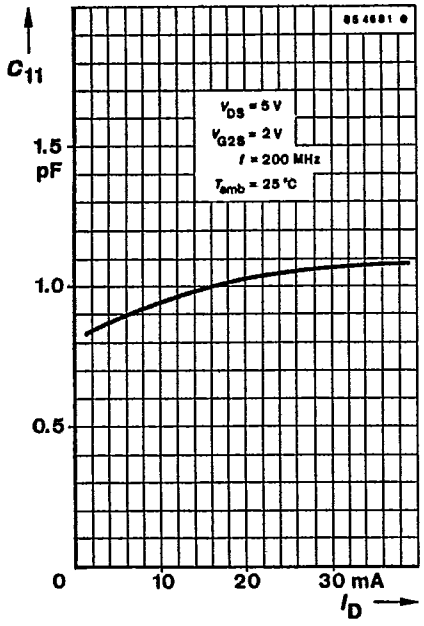

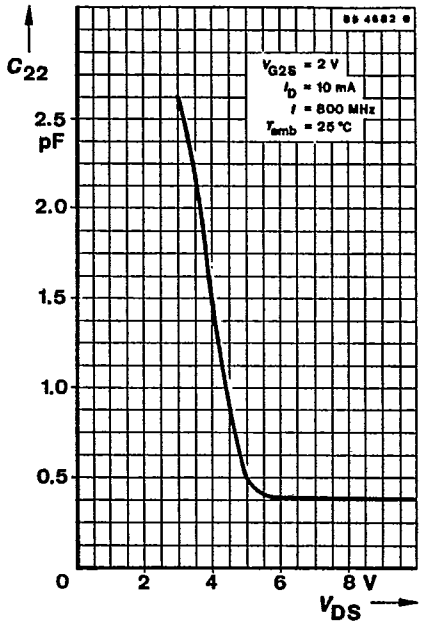

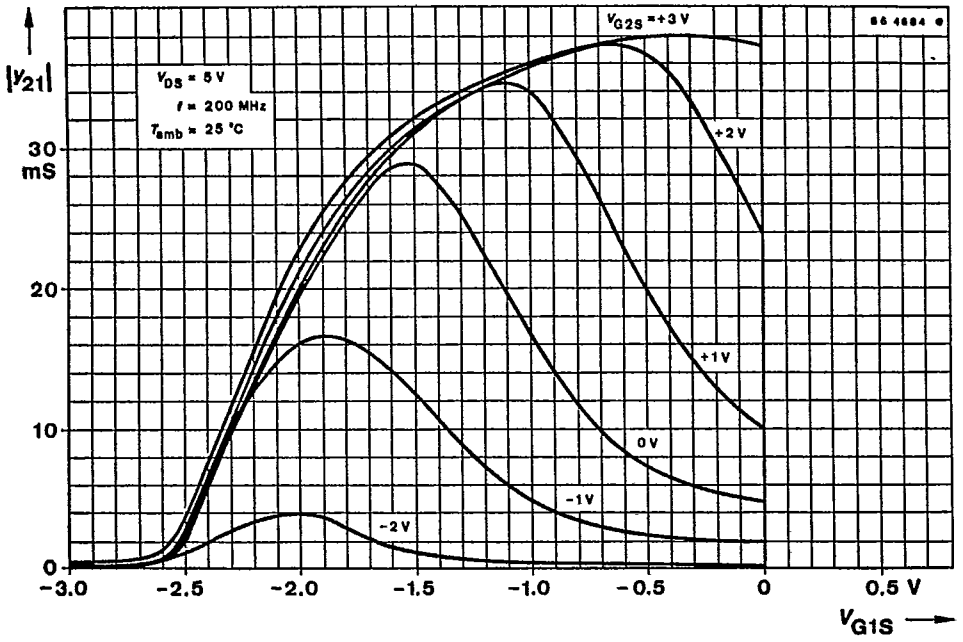

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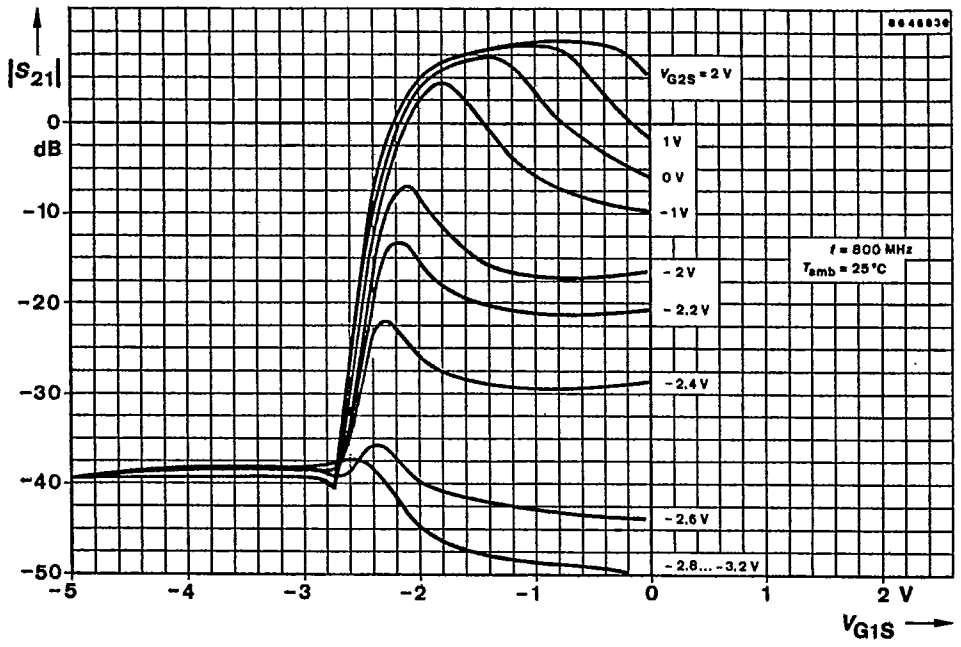
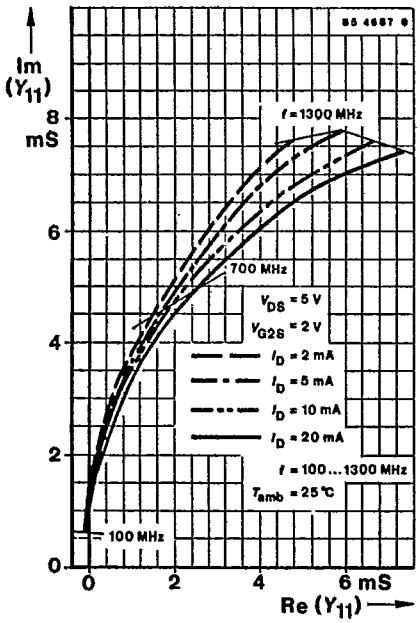
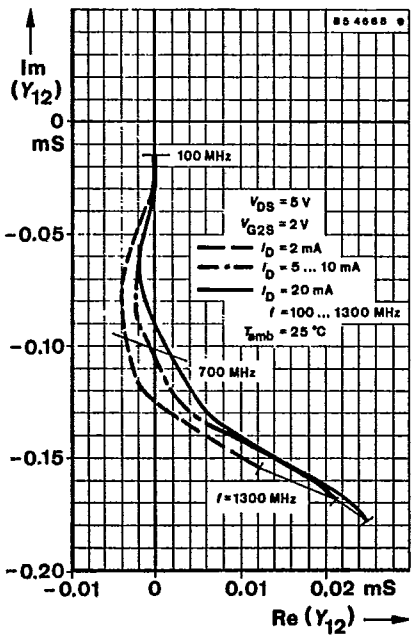

$|S_{21}|$
0
dB
-10
-20
-30
-40
-50
-5
-4
-3
-2
-1
0
1
2 V
V_{G1S}
V_{G2S} = 2 V
1 V
0 V
-1 V
- 2 V
- 2.2 V
- 2.4 V
- 2.6 V
- 2.8... - 3.2 V
f = 800 MHz
T_{amb} = 25 °C


Im (Y_{11})
8 mS
6
4
2
0
0
2
4
6 mS
Re (Y_{11})
f = 1300 MHz
700 MHz
100 MHz
V_{DS} = 5 V
V_{G2S} = 2 V
I_D = 2 mA
I_D = 5 mA
I_D = 10 mA
I_D = 20 mA
f = 100... 1300 MHz
T_{amb} = 25 °C


Im (Y_{12})
0
mS
-0.05
-0.10
-0.15
-0.20
-0.01
0
0.01
0.02 mS
Re (Y_{12})
100 MHz
700 MHz
f = 1300 MHz
V_{DS} = 5 V
V_{G2S} = 2 V
I_D = 2 mA
I_D = 5... 10 mA
I_D = 20 mA
f = 100... 1300 MHz
T_{amb} = 25 °C

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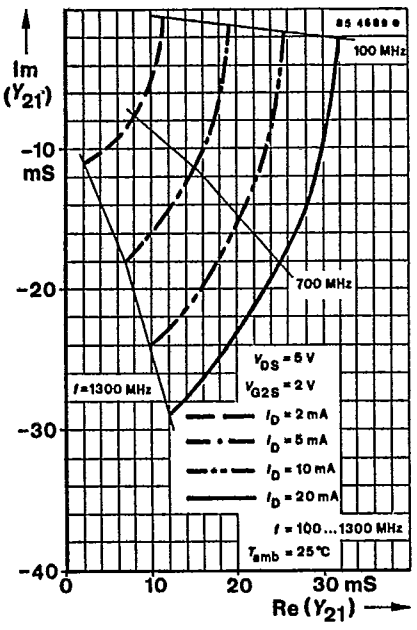
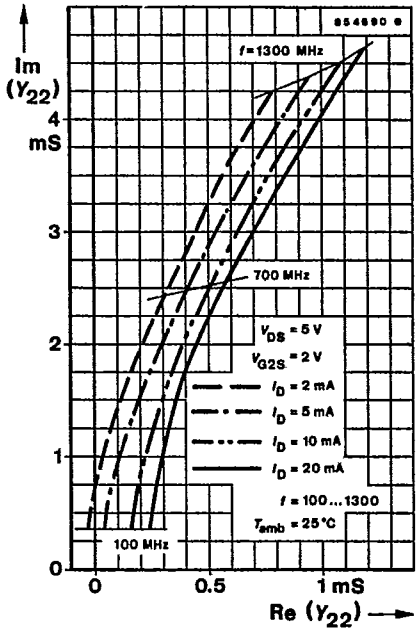
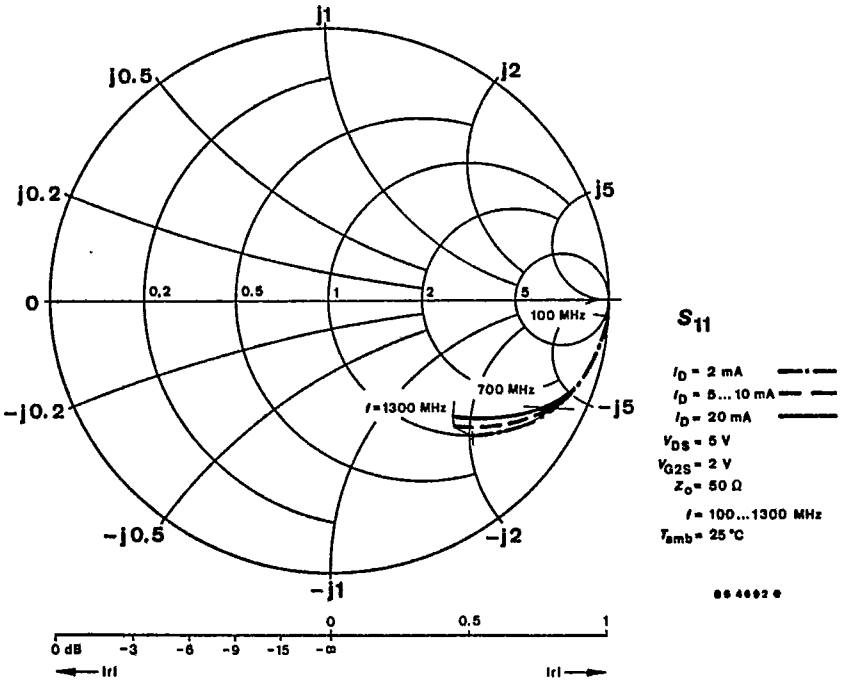

Im
(Y_{21})
-10
mS
-20
-30
-40
0
10
20
30 mS
Re (Y_{21})
100 MHz
700 MHz
f=1300 MHz
V_{DS} = 5 V
V_{G2S} = 2 V
I_D = 2 mA
I_D = 5 mA
I_D = 10 mA
I_D = 20 mA
f = 100...1300 MHz
T_{amb} = 25 °C


Im
(Y_{22})
4
mS
3
2
1
0
0
0.5
1 mS
Re (Y_{22})
f=1300 MHz
700 MHz
100 MHz
V_{DS} = 5 V
V_{G2S} = 2 V
I_D = 2 mA
I_D = 5 mA
I_D = 10 mA
I_D = 20 mA
f = 100...1300
T_{amb} = 25 °C


j1
j0.5
j2
j0.2
j5
0
0.2
0.5
1
2
5
100 MHz
700 MHz
f=1300 MHz
-j0.2
-j5
-j0.5
-j2
-j1
0
0.5
1
0 dB
-3
-6
-9
-15
-∞
|r|
|r|
S_{11}
I_D = 2 mA
I_D = 5...10 mA
I_D = 20 mA
V_{DS} = 5 V
V_{G2S} = 2 V
Z_o = 50 Ω
f = 100...1300 MHz
T_{amb} = 25 °C

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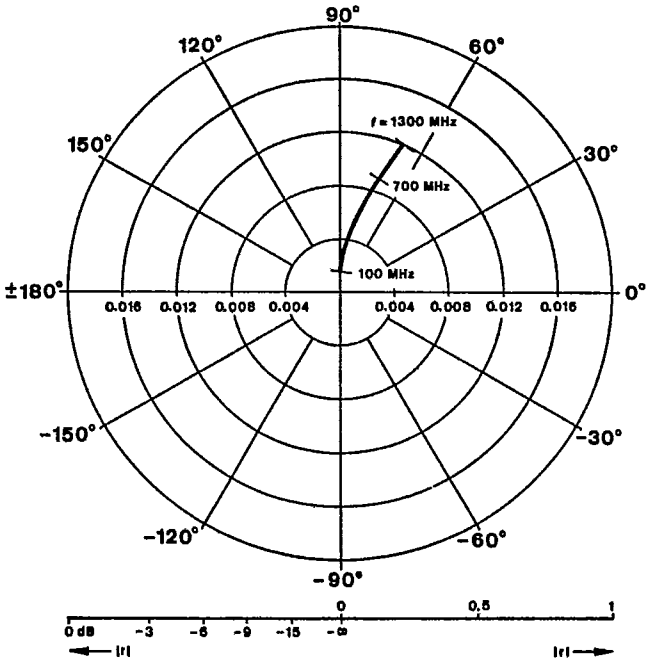
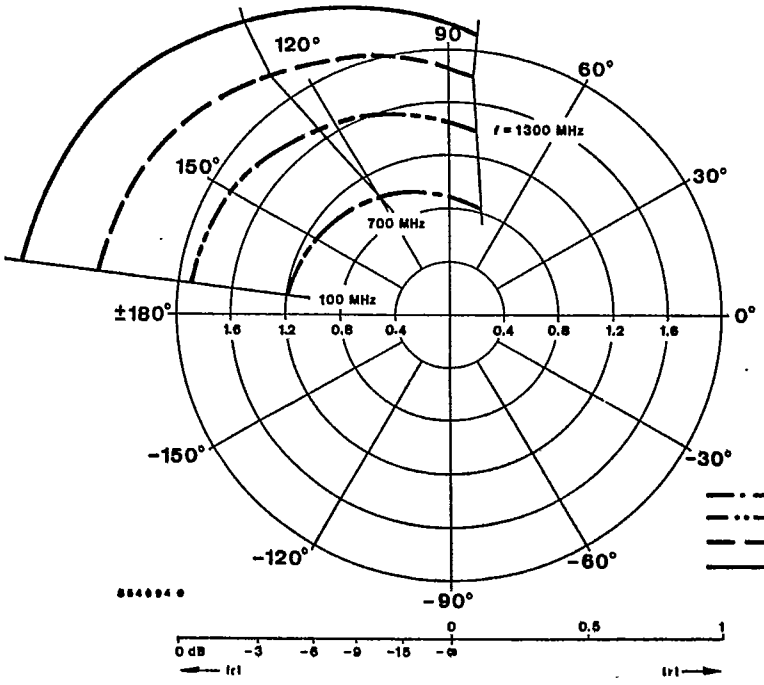


S_{12}

z_o = 50 Ω
V_{DS} = 5 V
V_{GS} = 2 V
I_D = 2 ... 20 mA
f = 100 ... 1300 MHz
T_{amb} = 25 °C

884693 e



884694 e

S_{21}

z_o = 50 Ω
V_{DS} = 5 V
V_{GS} = 2 V
I_D = 2 mA
I_D = 5 mA
I_D = 10 mA
I_D = 20 mA
f = 100 ... 1300 MHz
T_{amb} = 25 °C

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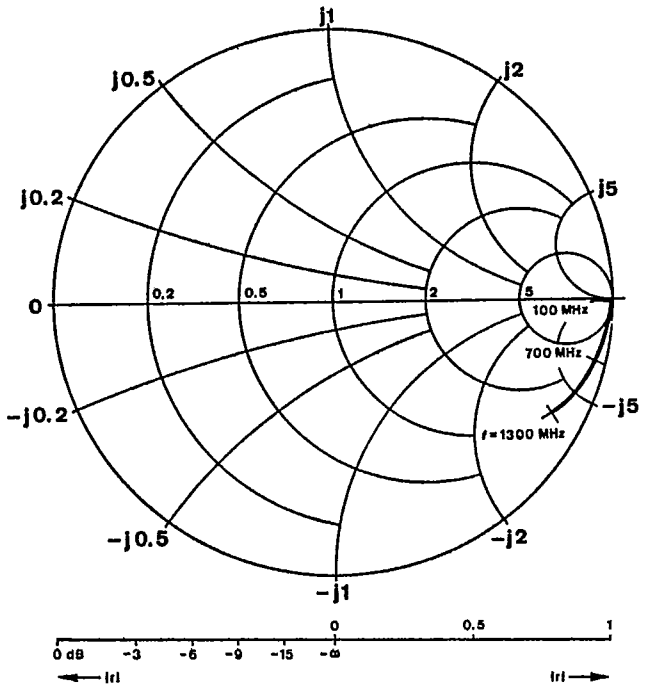
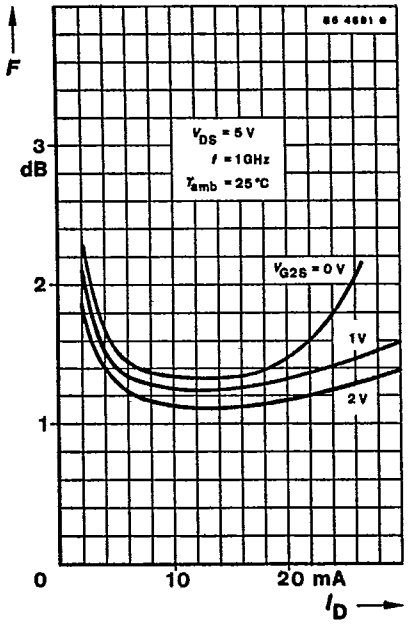


S_{22}

I_D = 2...20 mA
V_{DS} = 5 V
V_{G2S} = 2 V
Z_o = 50 Ω
f = 100... 1300 MHz
T_{amb} = 25 °C

B6 4695 e



7. Taping and Reeling

T-91-20

7.1. Taping of TO-92 Transistors

Standard reeling: Taped on reel, reeled together with a paper film.

7.1.1. Order Numbers
Add the taping-code to the order number.

Example:

BC 238 C DU 06 Z

- Order-No. of Type
- Code for TO-92 Transistors
- Orientation of transistor on tape [1]
- Additional marking for specials [2]

[1] 06 = View on flat side of transistor, view on gummed tape
05 = View on round side of transistor, view on gummed tape

[2] Additional marking "0": taping without paper film
Additional marking "Z": Zigzag folded tape in special box. Marking for orientation of transistor not necessary, because box can be opened on top or bottom

Example for order No.: BC 237 C DU Z

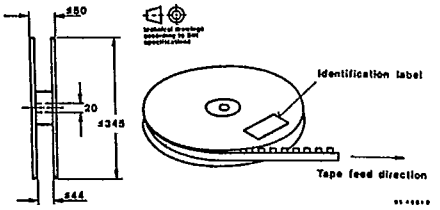


Fig. 7.1. Dimensions of reel in mm

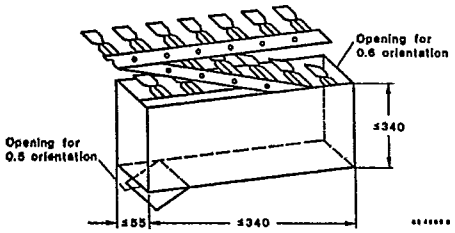


Fig. 7.2. Dimension of box for Zigzag folding in mm

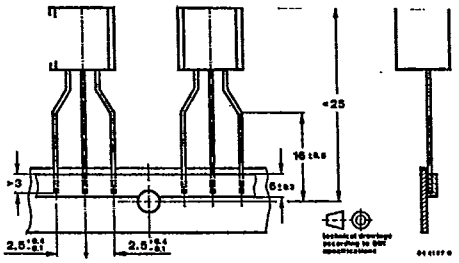


Fig. 7.3 Dimensions of tape in mm

7.1.2 Quantity of devices
1000 devices per reel
2000 devices per folded tape in special box.

7.2. Taped transistors in SOT 23 and SOT 143 case

7.2.1. Designation

a) Standard taping
Designation is attached with code GS 08 in case of standard taping. Example for normal version transistors as standard taped: BF 569-GS 08.

Example for R-version transistors as standard taped: BF 569 R-GS 08.

In case of standard taping, the transistor orientation on the tape is shown in Fig. 7.4 and Fig. 7.5.

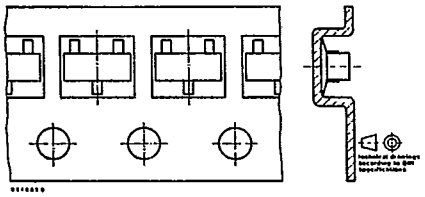


Fig. 7.4 Standard taped SOT 23

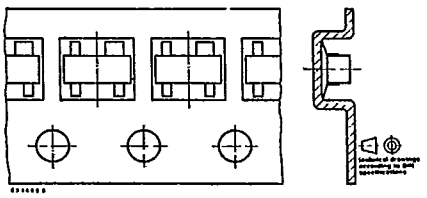


Fig. 7.5. Standard taped SOT 143

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b) Heverse taping

Designation is attached with code GS 07 in case of reverse taping. Example for normal version transistors as reverse taped: BF 569-GS 07.

Example for R-version transistors as reverse taping: BF 569 R-GS 07.

In case of reverse taping, the transistor orientation on the tape is shown in Fig. 7.6.

Regarding MOS-FET and MES-FET devices, reverse taping is at present not available.

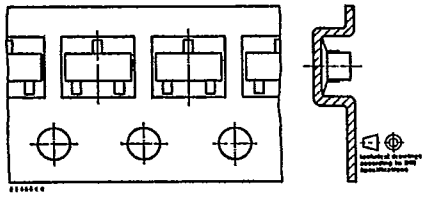

Fig. 7.6 Reverse taped SOT 23

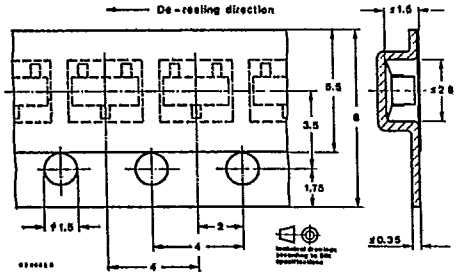

Fig. 7.7 Dimensions of tape in mm

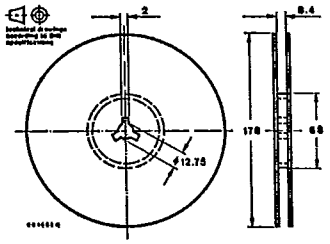

Fig. 7.8 Dimensions of reel in mm

7.2.2 Quantity of devices

3000 devices per reel